



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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Features

- $BV_{CEO} > -200V$
- $I_C = -2A$ High Continuous Collector Current
- $I_C = -5A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -165mV @ -1A$
- h_{FE} Specified up to $-5A$ for a High Gain Hold-Up

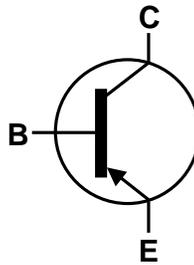
Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208⑥③
- Weight: 0.112 grams (Approximate)

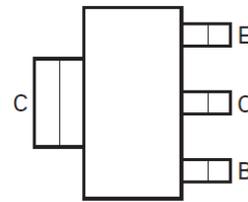
SOT223



Top View



Device Symbol



Top View
Pin-Out

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-220	V
Collector-Emitter Voltage	V _{CEO}	-200	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-2	A
Peak Pulse Current	I _{CM}	-5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

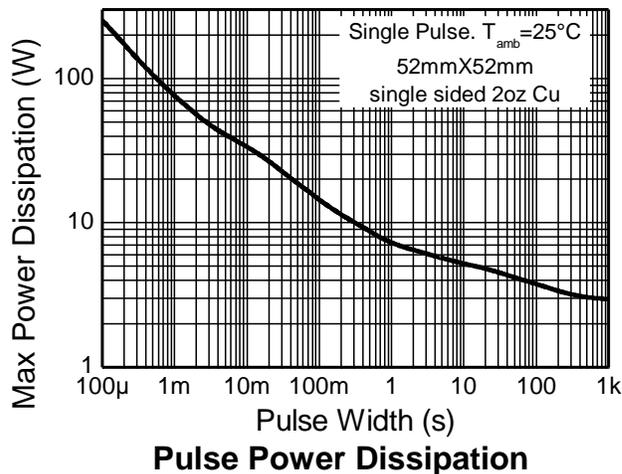
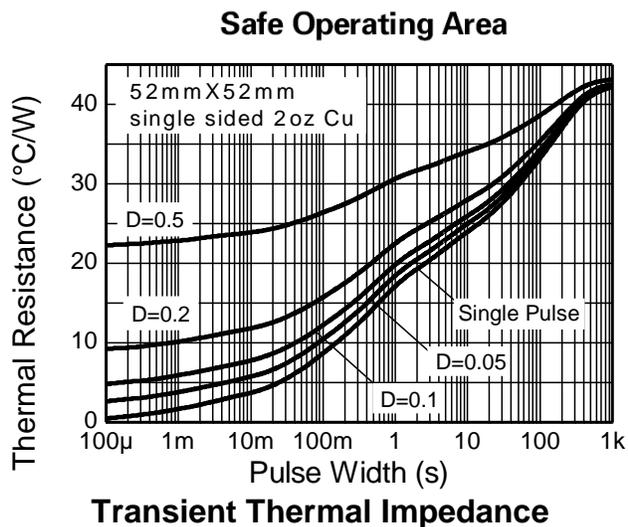
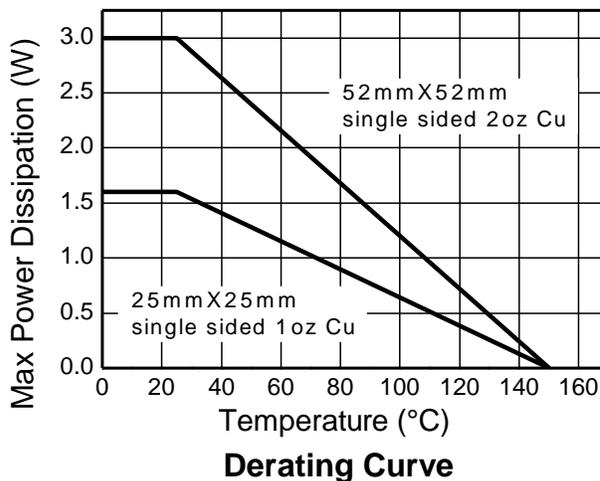
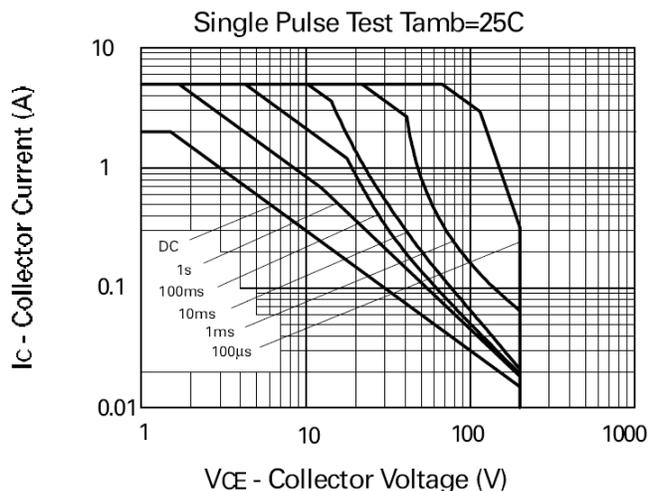
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P _D	3.0	W
		24	
Thermal Resistance, Junction to Ambient	R _{θJA}	1.6	mW /°C
		12.8	
Thermal Resistance Junction to Lead	R _{θJL}	42	°C/W
		78	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
 6. Same as Note 5, except mounted on 25mm x 25mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

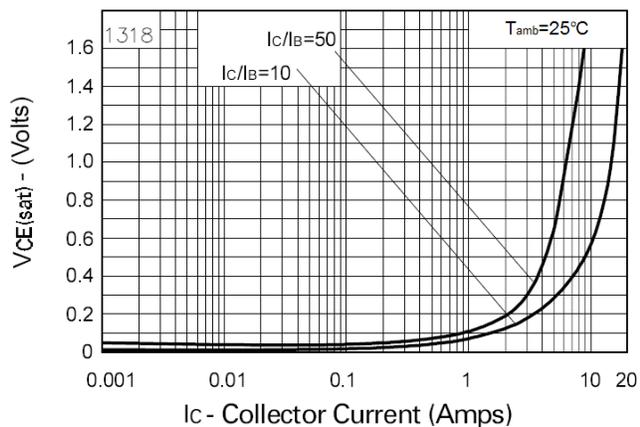


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

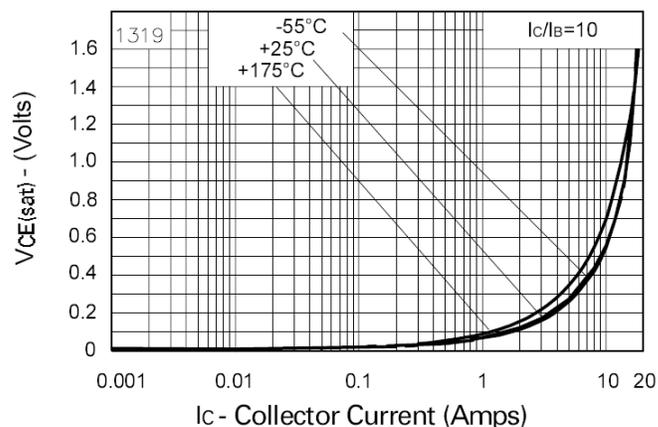
Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-220	-300	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CER}	-220	-300	—	V	I _C = -1μA, R _B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-200	-240	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.3	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	—	-50 -1	nA μA	V _{CB} = -200V V _{CB} = -200V, T _A = +100°C
Collector Cut-Off Current	I _{CER}	—	—	-50 -1	nA μA	V _{CE} = -200V, R ≤ 1kΩ V _{CE} = -200V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	—	—	-10	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 9)	h _{FE}	100	200	—	—	I _C = -10mA, V _{CE} = -5V
		100	200	300		I _C = -1A, V _{CE} = -5V
		50	150	—		I _C = -2A, V _{CE} = -5V
		—	10	—		I _C = -5A, V _{CE} = -5V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	-30	-50	mV	I _C = -100mA, I _B = -10mA
		—	-120	-165		I _C = -1A, I _B = -100mA
		—	-168	-275		I _C = -2A, I _B = -400mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	-970	-1,110	mV	I _C = -2A, I _B = -400mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	-810	-950	mV	I _C = -2A, V _{CE} = -5V
Transitional Frequency (Note 9)	f _T	—	110	—	MHz	I _C = -100mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	—	32	—	pF	V _{CB} = -20V, f = 1MHz
Switching Time	t _{on}	—	67	—	ns	V _{CC} = -50V, I _C = -1A, -I _{B1} = I _{B2} = -100mA
	t _{off}	—	1,140	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%. off

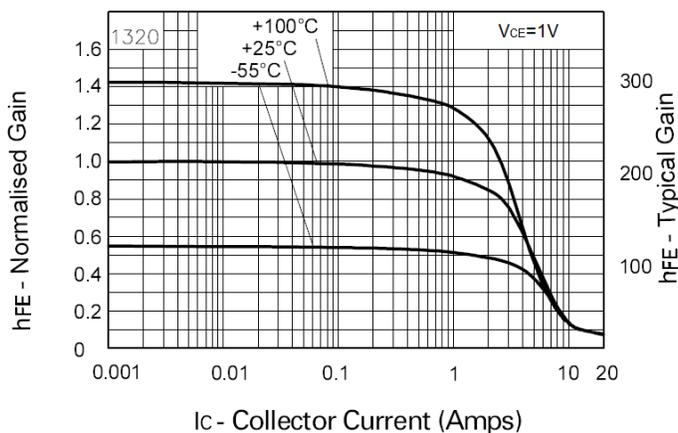
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



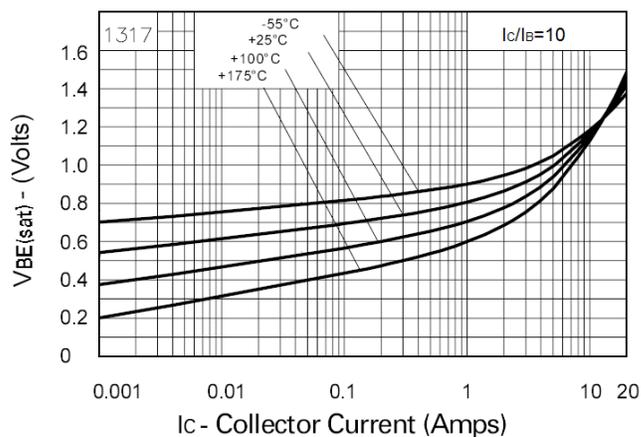
VCE(sat) v IC



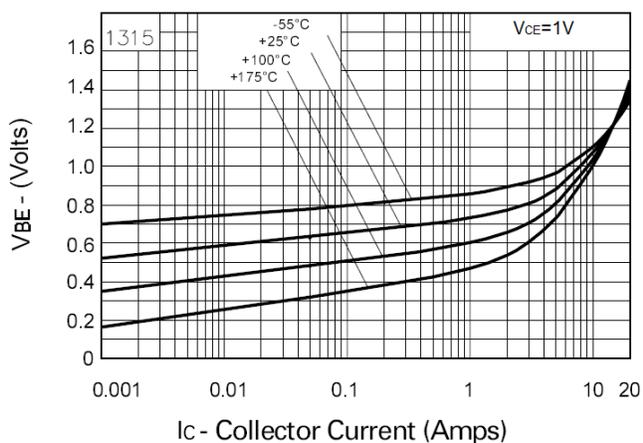
VCE(sat) v IC



hFE v IC



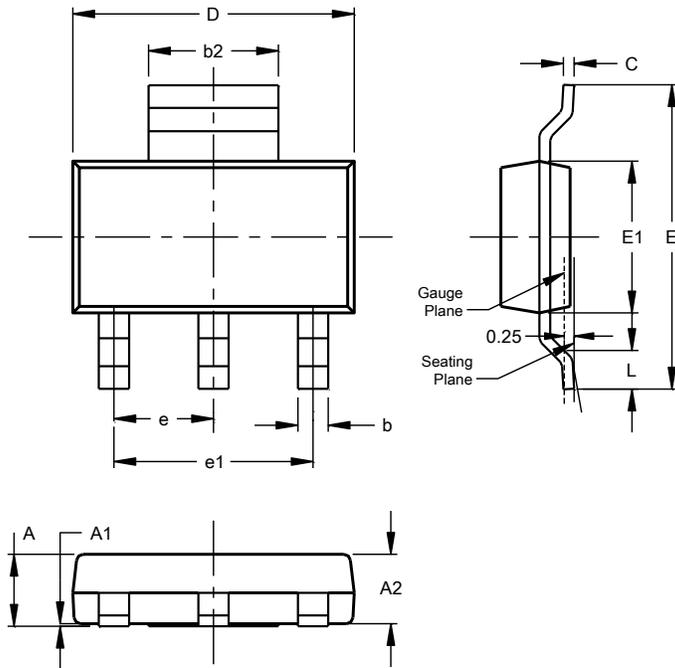
VBE(sat) v IC



VBE(on) v IC

Package Outline Dimensions

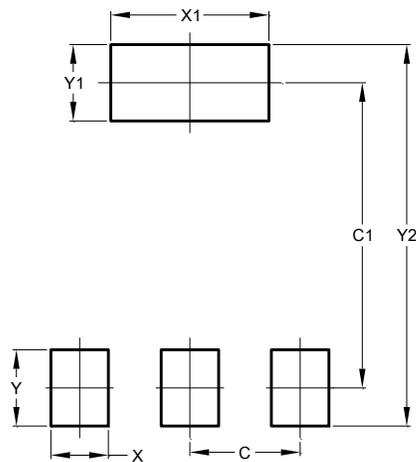
SOT223 (Type DN)



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Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00